# **AMPAK Technology Inc.**

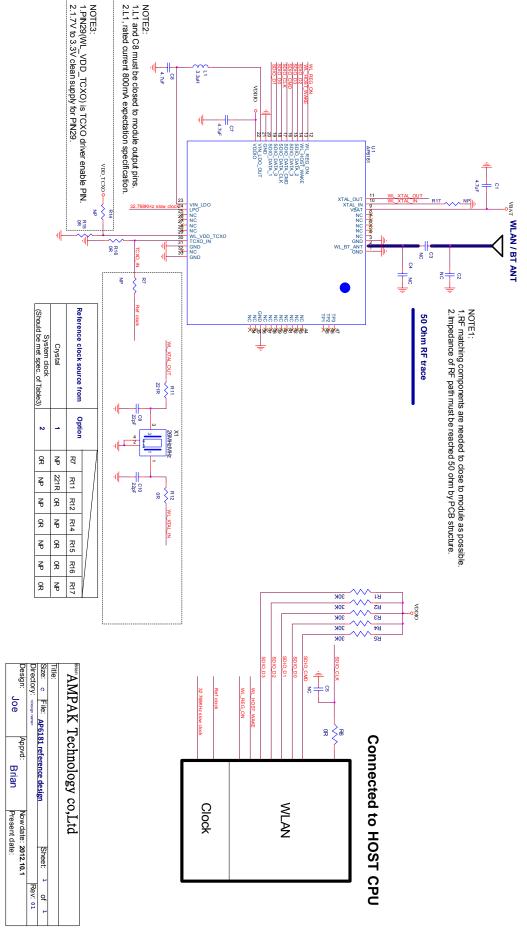
# Advanced Module Packaging Solution

# 正基科技股份有限公司

## **Revision History**

| Date       | Revision Content   | Revised By | Version |
|------------|--------------------|------------|---------|
| 2012/10/01 | - Initial released | Joe        | 1.0     |
|            |                    |            |         |
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|            |                    |            |         |

# AP6181 reference design circuit



### Note: Peripheral components highlight

| Item | Qty | Reference      | Value  | Description  | Vendor           |
|------|-----|----------------|--------|--|------------------|
| 1    | 3   | C1,C7,C8       | 4.7uF  | Capacitor 4.7uF 10V 10%(K) X5R 0805 T=1.25mm                             | Murata, WALSIN   |
| 2    | 2   | C9,C10         | 22pF   | Capacitor 22pF 50V 0.25P(C) NPO 0402 T=0.5mm                             | Murata, WALSIN   |
| 3    | 1   | L1             | 3.3uH  | Power Inductor (HF) 3.3uH 2.5*2.0mm Rated current 800mA                  | Murata, TDK      |
| 4    | 1   | R11            | 221R   | Resistor 221 ohm 1/16W 5% 0402   | YAGEO, WALSIN    |
| 5    | 5   | R1,R2,R3,R4,R5 | 30K    | Resistor 30K ohm 1/16W 5% 0402   | YAGEO, WALSIN    |
| 6    | 4   | R6,R12,R15,R16 | 0R     | Resistor 0 ohm 1/16W 5% 0402   | YAGEO, WALSIN    |
| 7    | 1   | X1             | 26MHz  | XTAL 26MHz+/-20ppm CL=16pF, ESR 60ohm(Max.) 3.2x2.5x0.55mm SMD -30~+85°C | HOSONIC, TAI-SAW |
| 8    | 1   | U1             | AP6181 | Module AP6181 WLBGA-44 802.11b/g/n 12x12 mm -30~+85℃                     | AMPAK            |

Table1. BOM

| Parameter                                    | Specification            | Units   |
|--|--------------------------|---------|
| Nominal input frequency                      | 32.768                   | kHz     |
| Frequency accuracy                           | ±30                      | ppm     |
| Duty cycle                                   | 30 - 70                  | %       |
| Input signal amplitude                       | 1600 to 3300             | mV, p-p |
| Signal type                                  | Square-wave or sine-wave | -       |
| Input impodence                              | >100k                    | Ω       |
| Input impedance                              | <5                       | pF      |
| Clock jitter (integrated over 300Hz – 15KHz) | <1                       | Hz      |
| Output high voltage                          | 0.7Vio - Vio             | V       |

Table2. 32.768KHz clock requirements and performance

### Peripheral interface highlight

❖ Power Source: A single host power supply can be used (including VBAT ranging from 3.0V to 4.8V) for AP6210 module and external VDDIO ranging from 1.71V to 3.6V supplies for GPIO by host power. Power topology is shown as below figure.

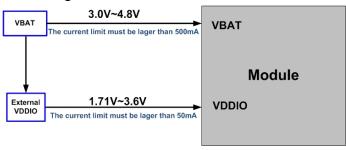


Figure 1. Power topology

Reference clock: About reference clock, as an alternative to a crystal, an external system clock can be used as the frequency reference, provided that it meets the phase noise requirements listed in table3 for WiFi requirements.

|  | Conditions/Notes                      | Crystal                                |     |     | Reference clock shared<br>from HOST system |          |                           |                   |
|--|---------------------------------------|--|-----|-----|--|----------|---------------------------|-------------------|
| Parameter  |                                       | Min                                    | Тур | Max | Min  | Тур      | Max                       | Units             |
| Frequency  | -                                     | Between 12 MHz and 52 MHz <sup>a</sup> |     |     |  |          |                           | 9                 |
| Crystal load<br>capacitance                          | -                                     | -                                      | 12  | -   |  |          |                           | pF                |
| ESR  | -                                     | -                                      | -   | 60  |  |          |                           | Ω                 |
| Input Impedance                                      | Resistive                             |  |     |     | 30k  | 100k     | ) <del>-</del>            | Ω                 |
| (OSCIN)b   | Capacitive                            |  |     |     | -  | ~- °     | 7.5                       | pF                |
| Input Impedance                                      | Resistive                             |  |     |     | 30k  | 100k     | -                         | Ω                 |
| (WRF_TCXO_IN)  | Capacitive                            |  |     |     | -1/2                                       | <b>_</b> | 4                         | pF                |
| OSCIN input voltage                                  | AC-coupled analog signal              |  |     |     | 400  | -        | 1200                      | mV <sub>p-p</sub> |
| OSCIN input low level                                | DC-coupled digital signal             |  |     |     | 0  | -        | 0.2                       | V                 |
| OSCIN input high level                               | DC-coupled digital signal             |  |     |     | 1.0  | -        | 1.36                      | V                 |
| WRF_TCXO_IN input voltage                            | DC-coupled analog signal <sup>c</sup> |  |     |     | 400  | -        | TCXO_<br>VDD <sup>d</sup> | mV <sub>p-p</sub> |
| Frequency tolerance<br>Initial + over<br>temperature | -                                     | -20                                    | -   | 20  | -20  | -        | 20                        | ppm               |
| Duty cycle   | 26 MHz clock                          |  |     |     | 40   | 50       | 60                        | %                 |
| Phase Noise <sup>e, f</sup>                          | 26 MHz clock at 1 kHz offset          |  |     |     | -  | -        | -119                      | dBc/Hz            |
| (IEEE 802.11 b/g)                                    | 26 MHz clock at 10 kHz offset         |  |     |     | -  | -        | -129                      | dBc/Hz            |
|  | 26 MHz clock at 100 kHz offset        |  |     |     | -  | -        | -134                      | dBc/Hz            |
|  | 26 MHz clock at 1 MHz offset          |  |     |     | -  | -        | -139                      | dBc/Hz            |
| Phase Noise <sup>e, f</sup>                          | 26 MHz clock at 1 kHz offset          |  |     |     | -  | -        | -124                      | dBc/Hz            |
| (IEEE 802.11n,                                       | 26 MHz clock at 10 kHz offset         |  |     |     | -  | -        | -134                      | dBc/Hz            |
| 2.4 GHz)   | 26 MHz clock at 100 kHz offset        |  |     |     | -  | -        | -139                      | dBc/Hz            |
|  | 26 MHz clock at 1 MHz offset          |  |     |     | -  | -        | -144                      | dBc/Hz            |

Table3. Crystal and eternal system clock requirements and performance for WiFi

WIFI SDIO: Using external pull up resistors depends on the SDIO supply voltage. For 1.8V, the resistance range is 30~82KΩ. For 2.6V, it range from 21~41 KΩ. For 3.3V, it range from 15~35 KΩ on the four data lines and the CMD line as the following circuitry.

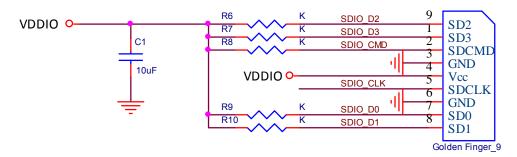


Figure 2.